## Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

## Listing of Claims:

Claims 1-15 (Canceled).

Claim 16 (Currently amended): A hydrogen reservoir comprising a substance suitable for storing hydrogen, said substance being made-up-ofis constituted by nano-structured silicon, wherein said nano-structured silicon is a nano-structure presenting a high specific surface area that is greater than  $100 \text{ m}^2/\text{cm}^3$ , wherein the nano-structure contains nano-crystallites or nano-particles of silicon of various geometric shapes that may be interconnected or not between themselves, of which at least one dimension is less than or equal to 100 nm and of which the sum of the surface areas of each nano-crystallite and/or nano-particle is greater than the plane surface occupied by the nano-structure.

Claim 17 (Currently amended): A hydrogen reservoir as claimed in claim 16, said substance being made-up of sconstituted by meso-porous and/or nano-porous silicon nanostructures.

Claim 18 (Currently amended): A hydrogen reservoir as claimed in claim 16, said substance being made-up-ofis constituted by nano-structured-silieon, porous and compacted silicon.

Claim 19 (Currently amended): A hydrogen reservoir as claimed in claim 16, said substance being made-up-ofis constituted by nano-structured-silieon, porous, ground and compacted silicon.

Claim 20 (Withdrawn): A manufacturing process for a hydrogen reservoir, comprising porosifying silicon in order to produce meso-porous and/or nano-porous silicon nano-structures and to store hydrogen in the nano-structures by creating chemical bonds between the hydrogen and the silicon. Claim 21 (Withdrawn): A manufacturing process as claimed in claim 20, wherein the creation of the chemical bonds between the hydrogen and the silicon is obtained through action of an acid.

Claim 22 (Withdrawn): A manufacturing process as claimed in claim 20, comprising subjecting monocrystalline, polycrystalline or amorphous silicon to an electrochemical anodisation implementing an acid and making it possible to simultaneously obtain the porosification of the silicon and the storage of the hydrogen.

Claim 23 (Withdrawn): A manufacturing process as claimed in claim 22, wherein the acid implemented is hydrofluoric acid.

Claim 24 (Withdrawn): A manufacturing process as claimed in claim 20, further comprising a subsequent step comprising compacting the nano-structured silicon.

Claim 25 (Withdrawn): A manufacturing process as claimed in claim 24, further comprising, before the compaction step, a step for grinding of the nano-structured silicon.

Claim 26 (Withdrawn): A method for extracting hydrogen from a hydrogen reservoir as claimed in claim 16, wherein hydrogen is stored in the hydrogen reservoir, the method comprising bringing about the breakage of the chemical bonds between the hydrogen and the silicon in order to extract the hydrogen.

Claim 27 (Withdrawn): A method for extracting hydrogen as claimed in claim 26, wherein the breakage of the chemical bonds between the hydrogen and the silicon is brought about by an input of energy chosen from among chemical energy, thermal energy, mechanical energy, radiant energy and the energy of an electric field.

Claim 28 (Withdrawn) A method for extracting hydrogen as claimed in claim 26, further comprising recharging the hydrogen reservoir by putting said substance in contact with an acid

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Claim 29 (Withdrawn): A fuel cell system or fuel cell including a hydrogen reservoir as claimed in claim 16.

Claim 30 (Withdrawn): A hydrogen motor system or hydrogen motor including a hydrogen reservoir as claimed in claim 16.